International Rectifier

MURD620CT

Ultrafast Rectifier

Features

- · Ultrafast Recovery Time
- · Low Forward Voltage Drop
- · Low Leakage Current
- 175°C Operating Junction Temperature

 $t_{rr} = 25 ns$

 $I_{F(AV)} = 6Amp$

 $V_{R} = 200V$

Description/Applications

International Rectifier's MUR.. series are the state of the art Ultra fast recovery rectifiers specifically designed with optimized performance of forward voltage drop and ultra fast recovery time. The planar structure and the platinum doped life time control, guarantee the best overall performance, ruggedness and reliability characteristics.

These devices are intended for use in the output rectification stage of SMPS, UPS, DC-DC converters as well as free-wheeling diode in low voltage inverters and chopper motor drives.

Their extremely optimized stored charge and low recovery current minimize the switching losses and reduce over dissipation in the switching element and snubbers.

Package Outline



Absolute Maximum Ratings

	Parameters		Max	Units
V _{RRM}	Peak Repetitive Peak Reverse Voltage		200	V
I _{F(AV)}	Average Rectified Forward Current	Per Device	6	Α
	Total Device, (Rated V _R), T _C = 146°C			
I _{FSM}	Non Repetitive Peak Surge Current		50	
I _{FM}	Peak Repetitive Forward Current	Per Diode	6	
	(Rated V_R , Square wave, 20 KHz), T_C = 146 $^{\circ}$ C			
T_J, T_{STG}	Operating Junction and Storage Temperatures		- 65 to 175	°C

Electrical Characteristics @ T_J = 25°C (unless otherwise specified)

Parameters	Min	Тур	Max	Units	Test Conditions				
Breakdown Voltage, Blocking Voltage	200	-	-	٧	Ι _R = 100μΑ				
Forward Voltage	-	-	1.0	V	I _F = 3A				
	-	-	0.96	V	I _F = 3A, T _J = 125°C				
	-	-	1.2	٧	I _F = 6A				
	-	-	1.13	٧	I _F = 6A, T _J = 125°C				
Reverse Leakage Current	-	-	5	μA	V _R = V _R Rated				
	-	-	250	μA	$T_J = 125^{\circ}C$, $V_R = V_R$ Rated				
Junction Capacitance	-	12	-	pF	V _R = 200V				
Series Inductance	-	8.0	-	nH	Measured lead to lead 5mm from package body				
	Parameters Breakdown Voltage, Blocking Voltage Forward Voltage Reverse Leakage Current Junction Capacitance	Parameters Min Breakdown Voltage, Blocking Voltage 200 Forward Voltage - - - - - - - - - - - - - - - Junction Capacitance -	Parameters Min Typ Breakdown Voltage, Blocking Voltage 200 - Forward Voltage - - - - - - - - - - - - - - Reverse Leakage Current - - Junction Capacitance - 12	Parameters Min Typ Max Breakdown Voltage, Blocking Voltage 200 - - Forward Voltage - - 1.0 - - 0.96 - - 1.2 - - 1.13 Reverse Leakage Current - 5 - - 250 Junction Capacitance - 12 -	Parameters Min Typ Max Units Breakdown Voltage, Blocking Voltage 200 - - V Forward Voltage - - 1.0 V - - 0.96 V - - 1.2 V - - 1.13 V Reverse Leakage Current - - 5 μA - - 250 μA Junction Capacitance - 12 - pF				

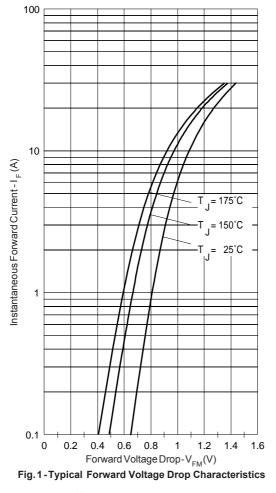
Dynamic Recovery Characteristics $@T_J = 25^{\circ}C$ (unless otherwise specified)

	Parameters	Min	Тур	Max	Units	Test Condition	s
t _{rr}	Reverse Recovery Time	-	-	35	ns	$I_F = 1.0A$, $di_F/dt = 50A/\mu s$, $V_R = 30V$	
		-	-	25		I _F = 0.5A, I _R = 1.0	A, I _{REC} = 0.25A
		-	19	-		T _J = 25°C	I _F = 3A
			26			T _J = 125°C	V _R = 160V
I _{RRM}	Peak Recovery Current	-	3.1	-	Α	T _J =25°C	di _F /dt = 200Α/μs
		-	4.6	-		T _J = 125°C	
Q _{rr}	Reverse Recovery Charge	-	30	-	nC	T _J =25°C	
		-	60	-		T _J = 125°C	

Thermal - Mechanical Characteristics

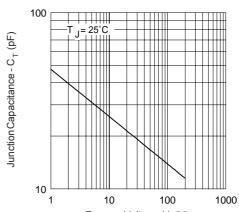
	Parameters		Min	Тур	Max	Units
TJ	Max. Junction Temperature Range		-	-	- 65 to 175	°C
T _{Stg}	Max. Storage Temperature Range		-	-	- 65 to 175	
R _{thJC}	Thermal Resistance, Junction to Case	PerLeg	-	-	9.0	°C/W
R _{thJA}	Thermal Resistance, Junction to Ambient	PerLeg	-	-	80	
R _{thCS} ^①	Thermal Resistance, Case to Heatsink		-	-	-	
Wt	Weight		-	0.3	-	g
			-	0.01	-	(oz)
	Mounting Torque		6.0	-	12	Kg-cm
			5.0	-	10	lbf.in

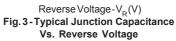
① Mounting Surface, Flat, Smooth and Greased



100 T_{.I} = 175°C 10 150°C Reverse Current - I R (µA) 125°C 100°C 0.1 0.01 25°C 0.001 50 100 150 200 Reverse Voltage- $V_R(V)$

Fig. 2-Typical Values Of Reverse Current Vs. Reverse Voltage





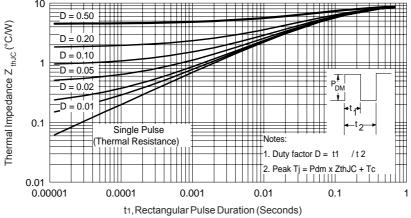


Fig. 4 - Max. Thermal Impedance Z_{thJC} Characteristics

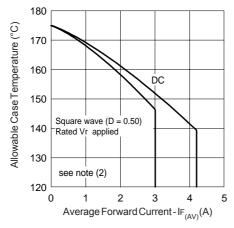


Fig. 5 - Max. Allowable Case Temperature Vs. Average Forward Current

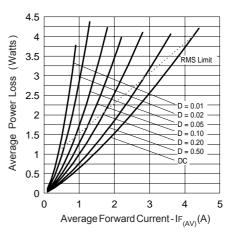


Fig. 6-Forward Power Loss Characteristics

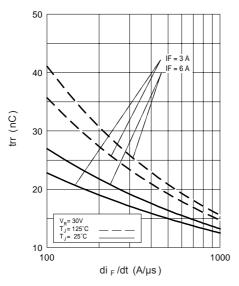


Fig. 7 - Typical Reverse Recovery vs. di _F/dt

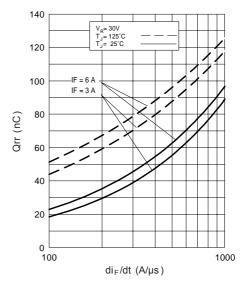


Fig. 8 - Typical Stored Charge vs. di $_{\text{F}}$ /dt

 $\begin{aligned} \textbf{(2)} \;\; &\text{Formula used: } \textbf{T}_{\text{C}} = \textbf{T}_{\text{J}} - (\text{Pd} + \text{Pd}_{\text{REV}}) \, \textbf{x} \, \textbf{R}_{\text{thJC}} \, ; \\ &\text{Pd} = \text{Forward Power Loss} = \textbf{I}_{\text{F(AV)}} \, \textbf{x} \, \textbf{V}_{\text{FM}} \, \textcircled{0} \, (\textbf{I}_{\text{F(AV)}} \, / \, \textbf{D}) \quad (\text{see Fig. 6}); \\ &\text{Pd}_{\text{REV}} = \text{Inverse Power Loss} = \textbf{V}_{\text{R1}} \, \textbf{x} \, \textbf{I}_{\text{R}} \, (\textbf{1} - \textbf{D}); \, \textbf{I}_{\text{R}} \, \textcircled{0} \, \textbf{V}_{\text{R1}} = \text{rated V}_{\text{R}} \end{aligned}$

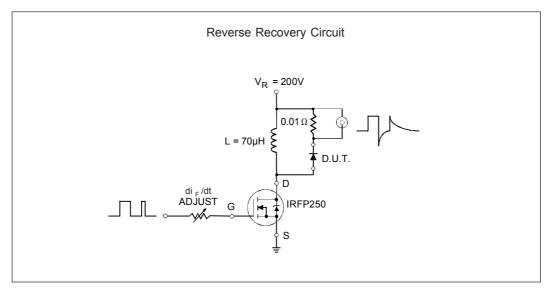


Fig. 9- Reverse Recovery Parameter Test Circuit

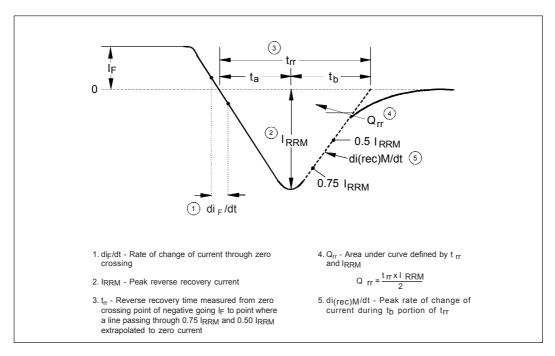
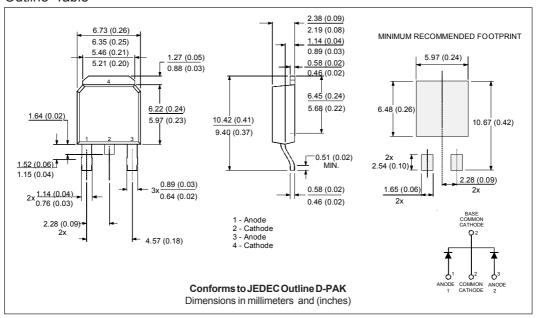


Fig. 10 - Reverse Recovery Waveform and Definitions

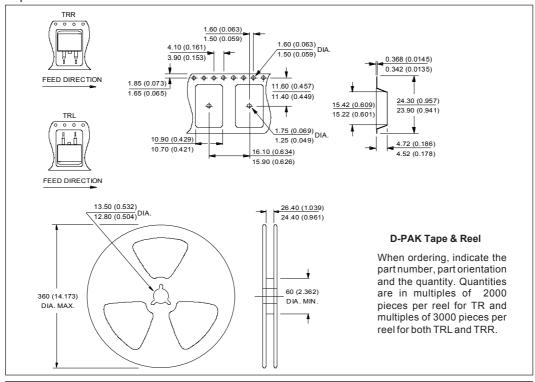
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Outline Table

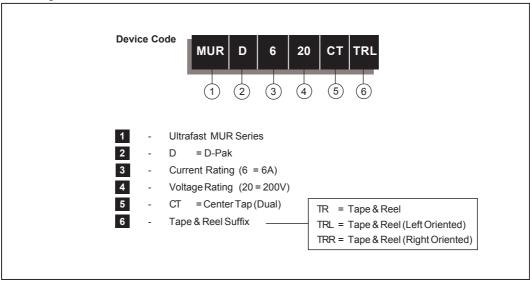


Tape & Reel Information



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Ordering Information Table



Data and specifications subject to change without notice. This product has been designed and qualified for Industrial Level. Qualification Standards can be found on IR's Web site.



IR WORLD HEADQUARTERS: 233 Kansas St., El Segundo, California 90245, USA Tel: (310) 252-7105 TAC Fax: (310) 252-7309

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Notice

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